

<b>MOSFET SPECIFICATIONS</b> $T_J = 25$ °C, unless otherwise noted										
Parameter	Symbol	Test Conditions		Min.	Typ. <sup>a</sup>	Max.	Unit			
Static										
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	Ch-1	0.8			V			
			Ch-2	1.0			<u> </u>			
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$	Ch-1			100	nA			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 24 V, V <sub>GS</sub> = 0 V	Ch-2 Ch-1			100	μΑ			
			Ch-2			100				
		V <sub>DS</sub> = 24 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 85 °C	Ch-1			15				
			Ch-2			2000				
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 10 V	Ch-1	20			A			
			Ch-2	30						
Drain-Source On-State Resistance <sup>b</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 6.3 \text{ A}$	Ch-1		0.018	0.022	Ω			
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 9.5 A	Ch-2		0.0125	0.0155				
		$V_{GS} = 4.5 \text{ V}, I_D = 5.4 \text{ A}$	Ch-1		0.024	0.030				
		$V_{GS} = 4.5 \text{ V}, I_D = 8.2 \text{ A}$	Ch-2		0.0165	0.0205				
Forward Transconductance <sup>b</sup>	g <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_D = 6.3 \text{ A}$	Ch-1		17		S			
		V <sub>DS</sub> = 15 V, I <sub>D</sub> = 9.5 A	Ch-2		28					
Diode Forward Voltage <sup>b</sup>	V <sub>SD</sub>	I <sub>S</sub> = 1.3 A, V <sub>GS</sub> = 0 V	Ch-1		0.7	1.1	V			
		I <sub>S</sub> = 1 A, V <sub>GS</sub> = 0 V	Ch-2		0.47	0.5				
Dynamic <sup>a</sup>										
Total Gata Chargo	Qq	Channel-1 V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 5 V, I <sub>D</sub> = 6.3 A	Ch-1		8.0	12	nC			
Total Gate Charge	₹g		Ch-2		15	23				
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 3 \text{ V}, I_D = 0.3 \text{ A}$ Channel-2 $V_{DS} = 15 \text{ V}, V_{GS} = 5 \text{ V}, I_D = -9.5 \text{ A}$	Ch-1		1.75					
date double charge			Ch-2		5.3					
Gate-Drain Charge	Q <sub>gd</sub>		Ch-1		3.2					
			Ch-2		4.6					
Gate Resistance	$R_g$		Ch-1	1.5		6.1	Ω			
			Ch-2	0.5		2.6				
Turn-On Delay Time Rise Time	t <sub>d(on)</sub>	Channel-1 $V_{DD}=15~V,~R_L=15~\Omega$ $I_D\cong 1~A,~V_{GEN}=10~V,~R_g=6~\Omega$	Ch-1		10	20	ns			
			Ch-2		15	30				
			Ch-1		5	10				
			Ch-2		5	10				
Turn-Off Delay Time Fall Time	t <sub>d(off)</sub>	$\label{eq:channel-2} \begin{split} & \text{Channel-2} \\ & \text{V}_{DD} = \text{15 V, R}_{L} = \text{15 } \Omega \\ & \text{I}_{D} \cong \text{1 A, V}_{GEN} = \text{10 V, R}_{g} = \text{6 } \Omega \end{split}$	Ch-1		26	50				
			Ch-2		44	80				
			Ch-1		8	16				
		1 40 4 31/1: 400 4/	Ch-2		12	24				
Source-Drain Reverse Recovery Time	t <sub>rr</sub> -	$I_F = 1.3 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$	Ch-1		30	60				
		$I_F = 2.2 \text{ A}, \text{ dI/dt} = 100 \mu\text{A/}\mu\text{s}$	Ch-2		32	70				

#### Notes

- a. Guaranteed by design, not subject to production testing.
- b. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

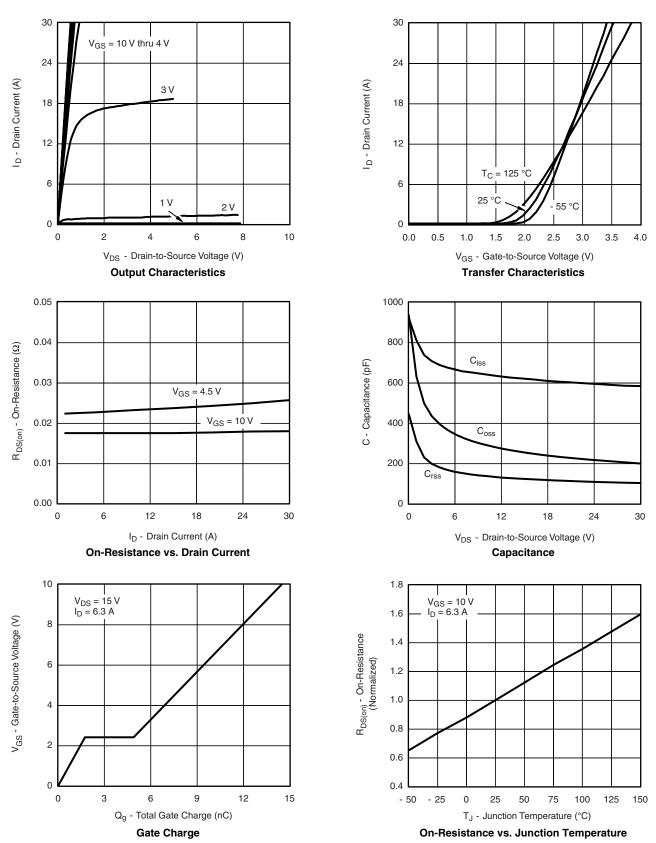
SCHOTTKY SPECIFICATIONS $T_J = 25$ °C, unless otherwise noted										
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit				
Forward Voltage Drop	V <sub>F</sub>	I <sub>F</sub> = 1.0 A		0.47	0.50	V				
		I <sub>F</sub> = 1.0 A, T <sub>J</sub> = 125 °C		0.36	0.42					
Maximum Reverse Leakage Current	I <sub>rm</sub>	V <sub>R</sub> = 30 V		0.004	0.100	mA				
		V <sub>R</sub> = 30 V, T <sub>J</sub> = 100 °C		0.7	10					
		$V_R = -30 \text{ V}, T_J = 125 ^{\circ}\text{C}$		3.0	20					
Junction Capacitance	C <sub>T</sub>	V <sub>R</sub> = 10 V		50		pF				

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





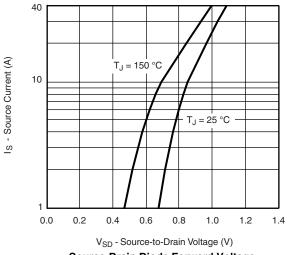
## CHANNEL-1 TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

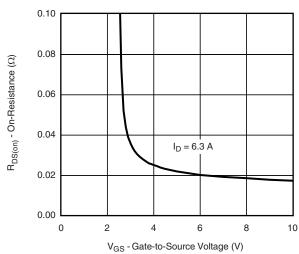


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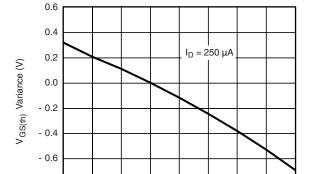
# VISHAY

# CHANNEL-1 TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

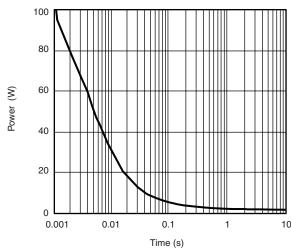




Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



T<sub>J</sub> - Temperature (°C)

Threshold Voltage

50

75

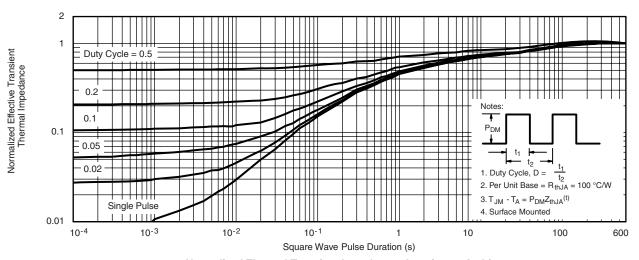
100

125

150

25





Normalized Thermal Transient Impedance, Junction-to-Ambient

- 0.8

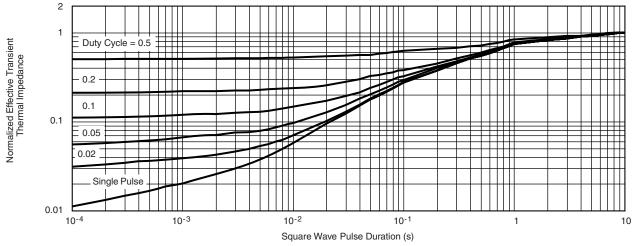
- 50

- 25



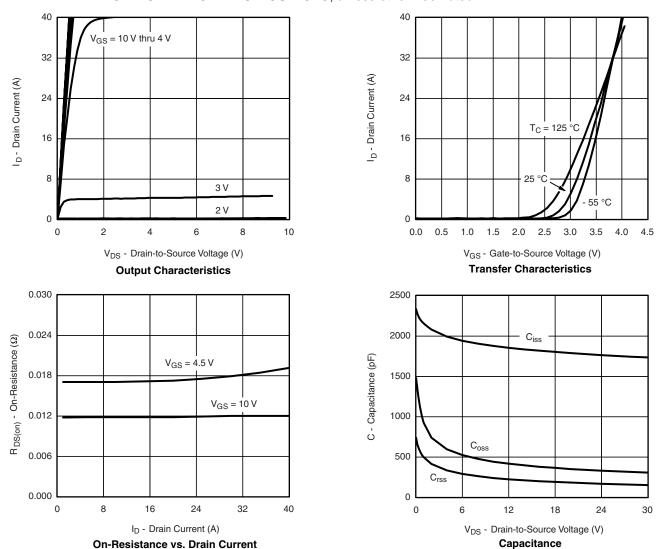


#### CHANNEL-1 TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

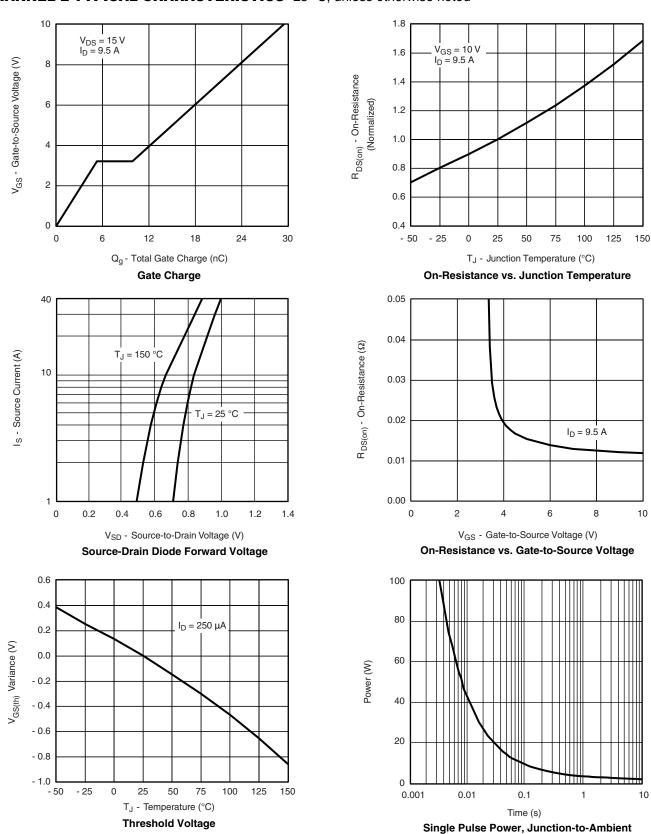
#### CHANNEL-2 TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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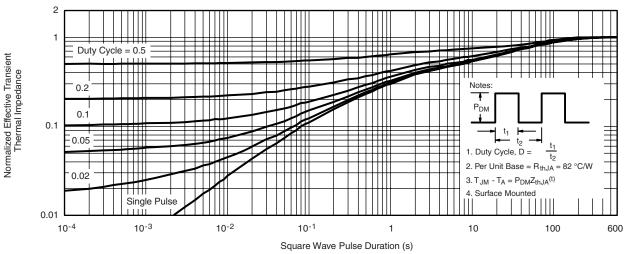
# CHANNEL-2 TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



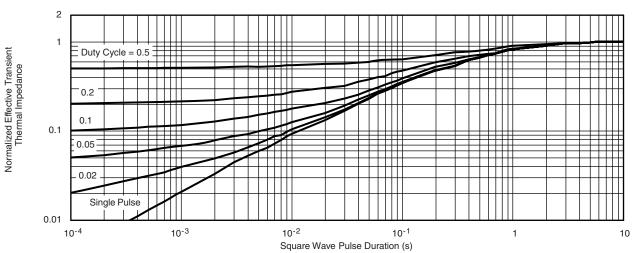




#### CHANNEL-2 TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

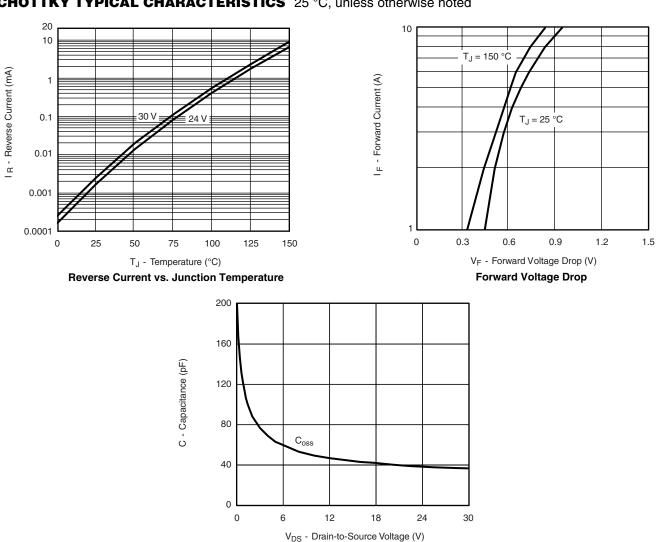


Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

## SCHOTTKY TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Capacitance

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